

Data Sheet January 2000 File Number 2779.4

### 15A, 200V Ultrafast Diodes

The MUR1520 and RURP1520 are ultrafast diodes ( $t_{rr}$  < 30ns) with soft recovery characteristics. They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

Formerly developmental type TA09926.

## **Ordering Information**

PART NUMBER	PACKAGE	BRAND
MUR1520	TO-220AC	MUR1520
RURP1520	TO-220AC	RURP1520

NOTE: When ordering, use the entire part number.

## Symbol



### **Features**

•	Ultrafast with Soft Recovery <30ns
•	Operating Temperature
•	Reverse Voltage

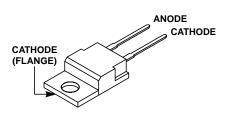
- Avalanche Energy Rated
- Planar Construction

## **Applications**

- · Switching Power Supply
- · Power Switching Circuits
- · General Purpose

### **Packaging**

**JEDEC TO-220AC** 



MIID1520

### **Absolute Maximum Ratings** $T_C = 25^{\circ}C$ , Unless Otherwise Specified

	RURP1520	UNITS
Peak Repetitive Reverse VoltageV <sub>RRM</sub>	200	V
Working Peak Reverse Voltage	200	V
DC Blocking Voltage	200	V
Average Rectified Forward Current	15	Α
Repetitive Peak Surge Current	30	Α
Nonrepetitive Peak Surge Current	200	Α
Maximum Power Dissipation	100	W
Avalanche Energy (See Figures 7 and 8)	20	mJ
Operating and Storage Temperature	-55 to 175	οС

**Electrical Specifications**  $T_C = 25^{\circ}C$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 15A	-	-	1.05	V
	$I_F = 15A, T_C = 150^{\circ}C$	-	-	0.85	V
I <sub>R</sub>	V <sub>R</sub> = 200V	-	-	100	μΑ
	$V_R = 200V, T_C = 150^{\circ}C$	-	-	500	μΑ
t <sub>rr</sub>	$I_F = 1A$ , $dI_F/dt = 100A/\mu s$	-	-	30	ns
	$I_F = 15A$ , $dI_F/dt = 100A/\mu s$	-	-	35	ns
t <sub>a</sub>	$I_F = 15A$ , $dI_F/dt = 100A/\mu s$	-	20	-	ns
t <sub>b</sub>	$I_F = 15A$ , $dI_F/dt = 100A/\mu s$	-	10	-	ns
R <sub>θJC</sub>		-	-	1.5	°C/W

### **DEFINITIONS**

 $V_F$  = Instantaneous forward voltage (pw = 300 $\mu$ s, D = 2%).

I<sub>R</sub> = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time at  $dI_F/dt$  = 100A/ $\mu$ s (See Figure 6), summation of  $t_a$  +  $t_b$ .

 $t_a$  = Time to reach peak reverse current at  $dI_F/dt$  = 100A/ $\mu$ s (See Figure 6).

t<sub>b</sub> = Time from peak I<sub>RM</sub> to projected zero crossing of I<sub>RM</sub> based on a straight line from peak I<sub>RM</sub> through 25% of I<sub>RM</sub> (See Figure 6).

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

# **Typical Performance Curves**

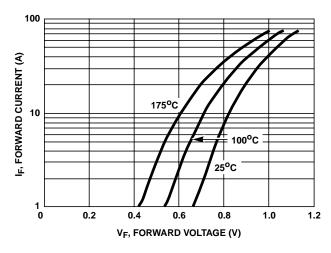


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

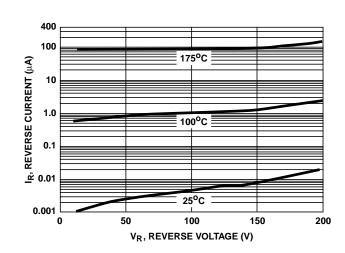


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

### Typical Performance Curves (Continued)

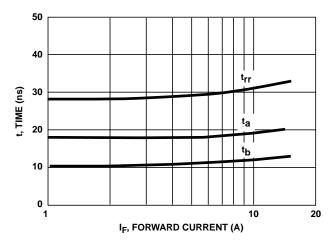


FIGURE 3. t<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT

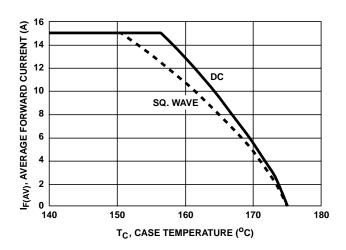


FIGURE 4. CURRENT DERATING CURVE

#### Test Circuits and Waveforms

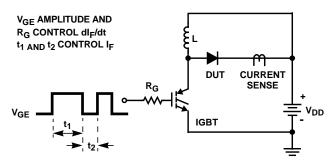


FIGURE 5. t<sub>rr</sub> TEST CIRCUIT

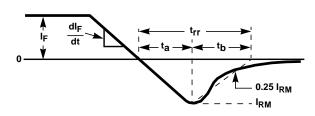


FIGURE 6. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

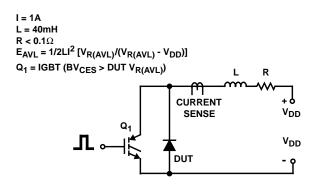


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

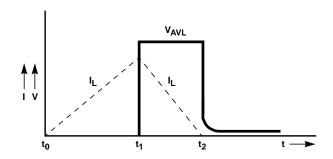


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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